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FFSH40120ADN_F155

Silicon Carbide Schottky Diode 1200 V, 40 A

Features

- Max Junction Temperature 175 °C
- · Avalanche Rated 200 mJ
- · High Surge Current Capacity
- · Positive Temperature Coefficient
- · Ease of Paralleling
- · No Reverse Recovery / No Forward Recovery

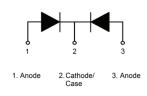
Applications

- · General Purpose
- · SMPS, Solar Inverter, UPS
- · Power Switching Circuits

Description

Silicon Carbide (SiC) Schottky Diodes use a completely new technology that provides superior switching performance and higher reliability compared to Silicon. No reverse recovery current, temperature independent switching characteristics, and excellent thermal performance sets Silicon Carbide as the next generation of power semiconductor. System benefits include highest efficiency, faster operating frequency, increased power density, reduced EMI, and reduced system size and cost.





Absolute Maximum Ratings T_C = 25°C unless otherwise noted. (per leg)

Symbol	Parameter	FFSH40120ADN_F155	Unit	
V_{RRM}	Peak Repetitive Reverse Voltage		1200	V mJ
= AS	Single Pulse Avalanche Energy	(Note 1)	200	
F	Continuous Rectified Forward Current @ T _C < 148 °C		20* / 40**	Α
I _{F, Max}	Non-Repetitive Peak Forward Surge Current	$T_C = 25 {}^{\circ}C$, 10 μs	1190	Α
		T _C = 150 °C, 10 μs	990	Α
F,SM	Non-RepetitiveForwardSurgeCurrent	Half-Sine Pulse, t_p = 8.3 ms	135	Α
F,RM	Repetitive Forward Surge Current	Half-Sine Pulse, $t_p = 8.3 \text{ ms}$	74	Α
Ptot	Dawer Dissipation	T _C = 25 °C	220	W
	Power Dissipation	T _C = 150 °C	37	W
T _J , T _{STG}	Operating and Storage Temperature Range		-55 to +175	°C
	TO247 Mounting Torque, M3 Screw	60	Ncm	

Thermal Characteristics

Symbol	Parameter	FFSH40120ADN_F155	Unit
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max.	0.68* / 0.34**	°C/W

^{*} Per Leg, ** Per Device

Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FFSH40120ADN_F155	FFSH40120ADN	TO-247 Long Lead	Tube	N/A	N/A	30 units

Electrical Characteristics $T_C = 25^{\circ}C$ unless otherwise noted. (per leg)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
V _F	Forward Voltage	$I_F = 20 \text{ A}, T_C = 25 {}^{\circ}\text{C}$	-	1.45	1.75	V
		$I_F = 20 \text{ A}, T_C = 125 ^{\circ}\text{C}$	-	1.7	2	
		$I_F = 20 \text{ A}, T_C = 175 ^{\circ}\text{C}$	-	2	2.4	
I _R	Reverse Current	VR = 1200 V, T _C = 25 °C	-	-	200	μА
		VR = 1200 V, T _C = 125 °C	-	-	300	
		VR = 1200 V, T _C = 175 °C	-	-	400	
Q_C	Total Capacitive Charge	V = 800 V	-	120	-	nC
С	Total Capacitance	V _R = 1 V, f = 100 kHz	-	1220	-	pF
		V _R = 400 V, f = 100 kHz	-	111	-	
		V _R = 800 V, f = 100 kHz	-	88	-	

Typical Characteristics T_J = 25 °C unless otherwise noted (per leg).

Figure 1. Forward Characteristics

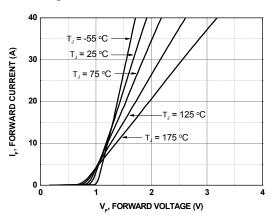


Figure 2. Reverse Characteristics

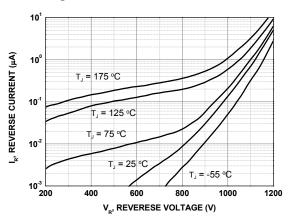


Figure 3. Reverse Characteristics

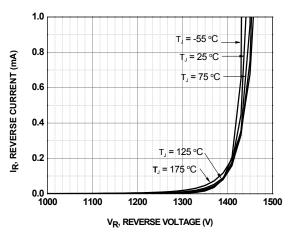
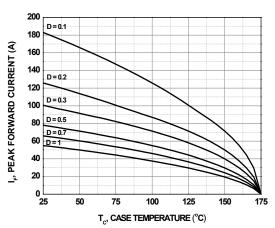


Figure 4. Current Derating



Notes:
1: EAS of 200mJ is based on starting T_J = 25 °C, L = 0.5 mH, I_{AS} = 29 A, V = 150 V.

Typical Characteristics $T_J = 25$ °C unless otherwise noted (per leg, continue).

Figure 5. Power Derating

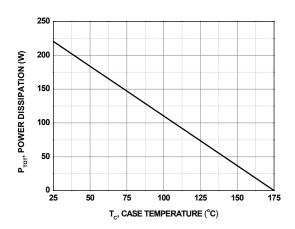


Figure 6. Capacitive Charge vs. Reverse Voltage

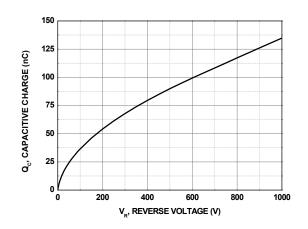


Figure 7. Capacitance vs. Reverse Voltage

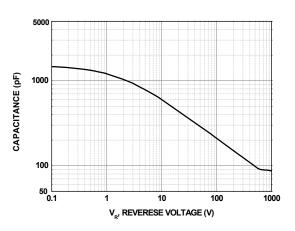


Figure 8. Capacitance Stored Energy

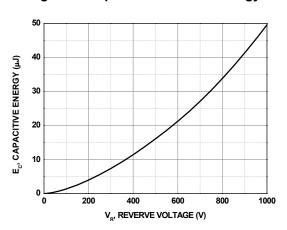
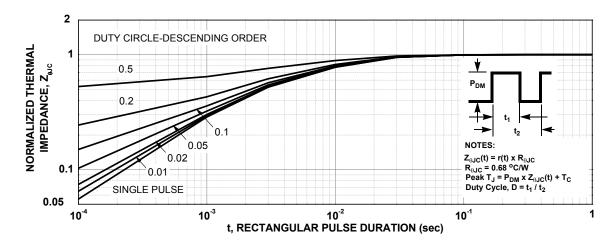
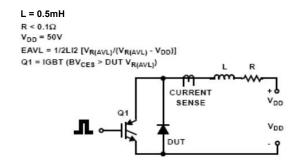


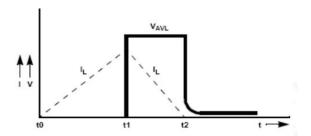
Figure 9. Junction-to-Case Transient Thermal Response Curve

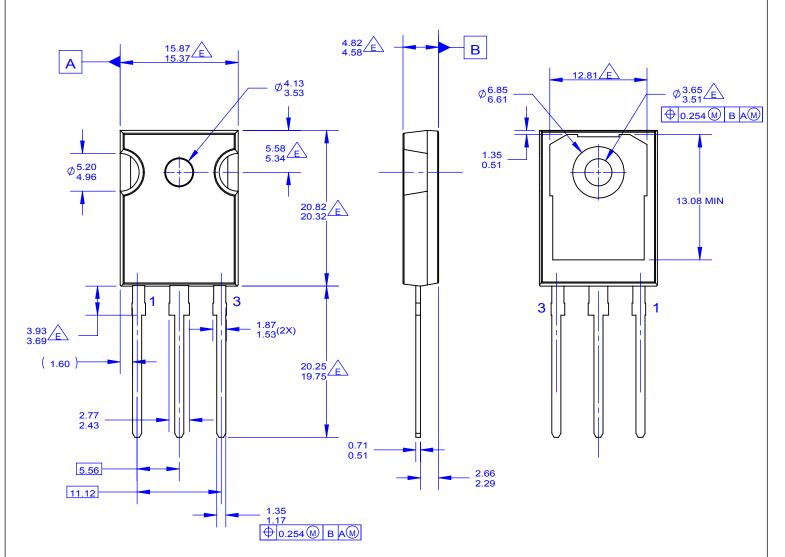


Test Circuit and Waveforms

Figure 10. Unclamped Inductive Switching Test Circuit & Waveform







NOTES: UNLESS OTHERWISE SPECIFIED.

- A. PACKAGE REFERENCE: JEDEC TO-247, ISSUE E, VARIATION AB, DATED JUNE, 2004.
- B. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.
- C. ALL DIMENSIONS ARE IN MILLIMETERS.
- D. DRAWING CONFORMS TO ASME Y14.5 1994





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